Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-007-6855

**Inclosure Material:** Metal **Overall Length:** 2.500 inches **Overall Height:** 2.500 inches **Mounting Facility Quantity:** 1 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.063 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 720.0 breakover voltage, dc **Current Rating Per Characteristic:** 1800.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector blank Maximum Operating Tempurature Per Measurement Point: 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 uninsulated wire lead Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0